

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

February 2001 Revised May 2005

FAIRCHILD

SEMICONDUCTOR

74LCX162373

Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs and 26 Ω Series Resistor

General Description

The LCX162373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the outputs are in a high impedance state.

The LCX162373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The 26Ω series resistor in the output helps reduce output overshoot and undershoot.

The LCX162373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- Equivalent 26Ω series resistor outputs
- 6.2 ns t_{PD} max (V_{CC} = 3.3V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±12 mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance: Human body model > 2000V
 - Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

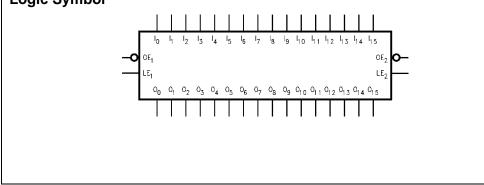
Ordering Code:

Order Number	Package Number	Package Description
74LCX162373GX (Note 2)	BGA54A (Preliminary)	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide [TAPE and REEL]
74LCX162373MEA (Note 3)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX162373MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: BGA package available in Tape and Reel only.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



www.fairchildsemi.com

'4LCX162373 Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs and 26 Ω Series Resisto

74LCX162373

Connection Diagrams

Pin Assignment for SSOP and TSSOP 0E1 48 - LE₁ 47 00. - 1₀ 46 – կ 01. GND -45 - GND 02 44 5 - I₂ 03. 43 6 - I₃ v_{cc} 42 - v_{cc} 41 04 8 - I₄ 40 0₅ -- I₅ GND 10 39 – GND 06. 38 11 - I₆ 07 12 37 - 1₇ 36 08 13 - 1₈ 35 14 0q - I₉ GND 15 34 – GND 010 16 33 - I₁₀ 32 17 011 - 41 31 V_{CC} 18 – v_{cc} 19 30 - I_{1 2} 0_{1 2} 0₁₃ -20 29 - 4 3 GND・ 21 28 – GND 22 27 014 - I_{1 4} 015 23 26 - I₁₅ 0E2 25 24 - LE₂ Pin Assignment for FBGA 1 2 3 4 5 6 < ш 000000 υ 000000 Ω 000000 ш ш 000000 G 000000 000000 т 000000 -(Top Thru View)

Pin Descriptions

Pin Names	Description
0E _n	Output Enable Input (Active LOW)
LEn	Latch Enable Input
I ₀ —I ₁₅	Inputs
O ₀ -O ₁₅ NC	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	LE ₁	NC	I ₀
В	0 ₂	0 ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	l ₃	I ₄
D	O ₆	O ₅	GND	GND	I ₅	I ₆
E	0 ₈	0 ₇	GND	GND	۱ ₇	۱ ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	O ₁₂	O ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
н	0 ₁₄	0 ₁₃	NC	NC	I ₁₃	I ₁₄
J	O ₁₅	NC	OE ₂	LE_2	NC	I ₁₅

Truth Tables

	Inputs		Outputs
LE ₁	OE ₁	I ₀ –I ₇	0 ₀ –0 ₇
Х	Н	Х	Z
н	L	L	L
н	L	н	н
L	L	Х	O ₀
	Inputs		Outputs
LE ₂	0E2	I ₈ —I ₁₅	0 ₈ –0 ₁₅
Х	Н	Х	Z
н	L	L	L
н	L	н	н
		х	O ₀

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial Z = High Impedance

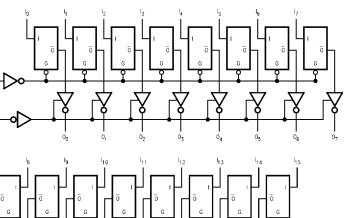
 $O_0 = Previous O_0$ before HIGH-to-LOW transition of Latch Enable

Functional Description

The LCX162373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time

its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the standard outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams



014

015

013

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

012

011

010

74LCX162373

74LCX162373

Absolute Maximum Ratings(Note 4)

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		–0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 5)	
lıк	DC Input Diode Current	-50	V _I < GND	mA
ок	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	IIIA
l ₀	DC Output Source/Sink Current	±50		mA
cc	DC Supply Current per Supply Pin	±100		mA
GND	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 6)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		12	
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±8	mA
		$V_{CC} = 2.3V - 2.7V$		±4	
Τ _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C$	to +85°C	Units
Symbol	Farameter	Conditions	(V)	Min	Max	onita
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	1.8		v
		$I_{OH} = -4 \text{ mA}$	2.7	2.2		
		$I_{OH} = -6 \text{ mA}$	3.0	2.4		
		I _{OH} = -8 mA	2.7	2.0		
		$I_{OH} = -12 \text{ mA}$	3.0	2.0		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		$I_{OL} = 4 \text{ mA}$	2.3		0.6	
		$I_{OL} = 4 \text{ mA}$	2.7		0.4	v
		$I_{OL} = 6 \text{ mA}$	3.0		0.55	v
		I _{OL} = 8 mA	2.7		0.6	
		I _{OL} = 12 mA	3.0		0.8	
lı –	Input Leakage Current	$0 \leq V_I \leq 5.5 V$	2.3 - 3.6		±5.0	μA
l _{oz}	3-STATE Output Leakage	$0 \le V_O \le 5.5 V$	2.3 - 3.6		±5.0	
		$V_I = V_{IH} \text{ or } V_{IL}$				μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
	Faranieler	Conditions	(V)	Min	Max	Units
I _{OFF}	Power-Off Leakage Current	V _I or V _O = 5.5V	0		10	μA
Icc	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	
		$3.6V \leq V_I, \ V_O \leq 5.5V \ (\text{Note 7})$	2.3 – 3.6		±20	μA
∆l _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

			T _A	= -40°C to +	-85°C, R _L = 50	00 Ω		
Symbol	Parameter	V _{CC} = 3.	$.3V \pm 0.3V$	V _{CC}	= 2.7V	V _{CC} = 2.4	5V ± 0.2V	Units
		C _L =	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF	
		Min	Max	Min	Max	Min	Max	-
t _{PHL}	Propagation Delay	1.5	6.2	1.5	6.7	1.5	7.4	ns
t _{PLH}	I _n to O _n	1.5	6.2	1.5	6.7	1.5	7.4	115
t _{PHL}	Propagation Delay	1.5	6.3	1.5	7.2	1.5	7.6	ns
t _{PLH}	LE to O _n	1.5	6.3	1.5	7.2	1.5	7.6	115
t _{PZL}	Output Enable Time	1.5	6.9	1.5	7.3	1.5	9.0	ns
t _{PZH}		1.5	6.9	1.5	7.3	1.5	9.0	115
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	ns
t _{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	115
t _S	Setup Time, In to LE	2.5		2.5		3.0		ns
t _H	Hold Time, I _n to LE	1.5		1.5		2.0		ns
t _W	LE Pulse Width	3.0		3.0		3.5		ns
t _{OSHL}	Output to Output Skew (Note 8)		1.0					ns
t _{OSLH}			1.0					113

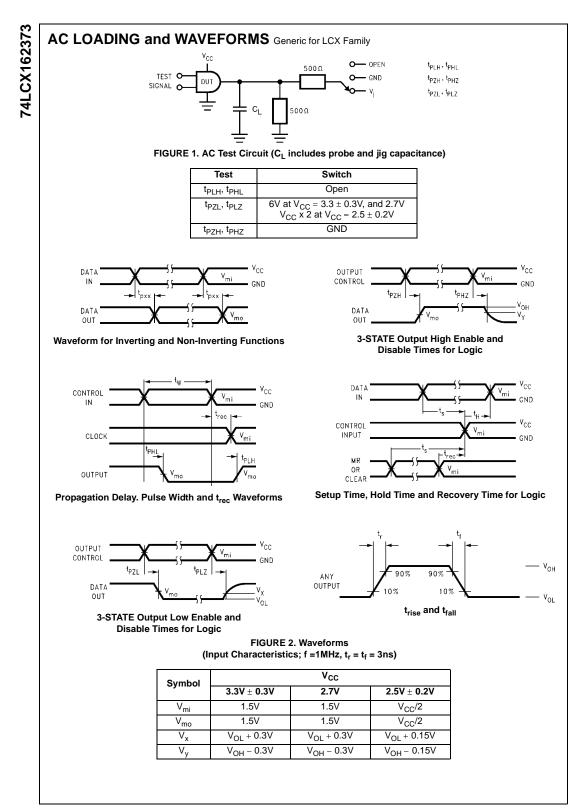
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

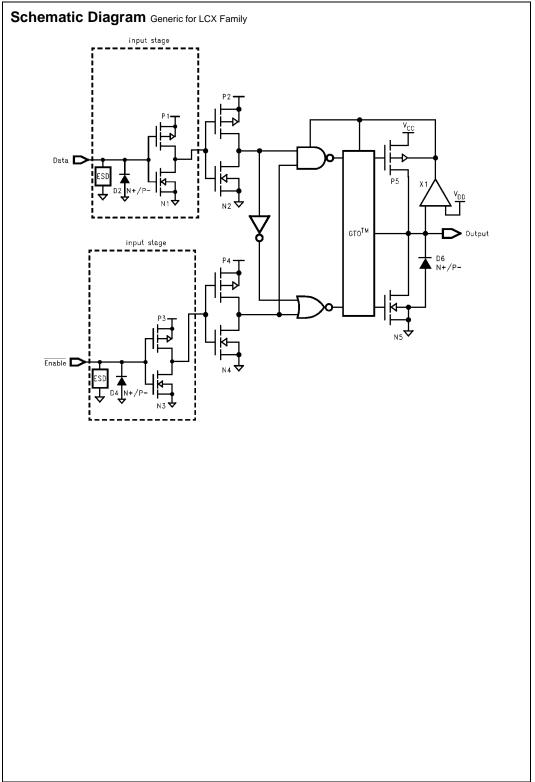
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC}	$T_A = 25^\circ C$	Units
Symbol	Falanielei	Conditions	(V)	Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V}$	3.3	0.35	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.25	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_{L} = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V}$	3.3	-0.35	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.25	~

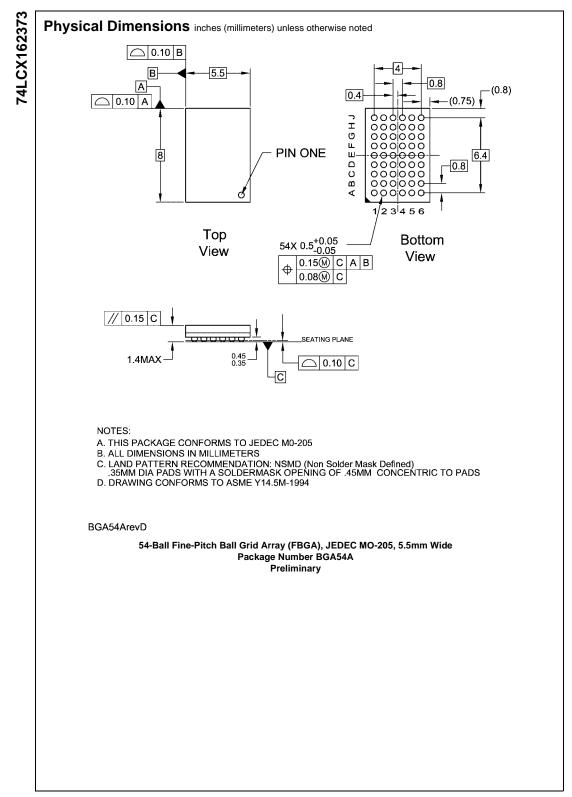
Capacitance

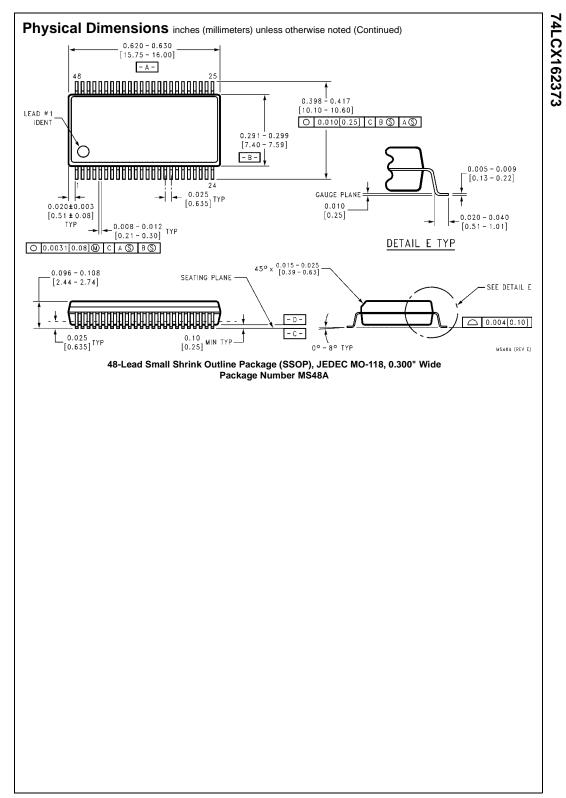
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

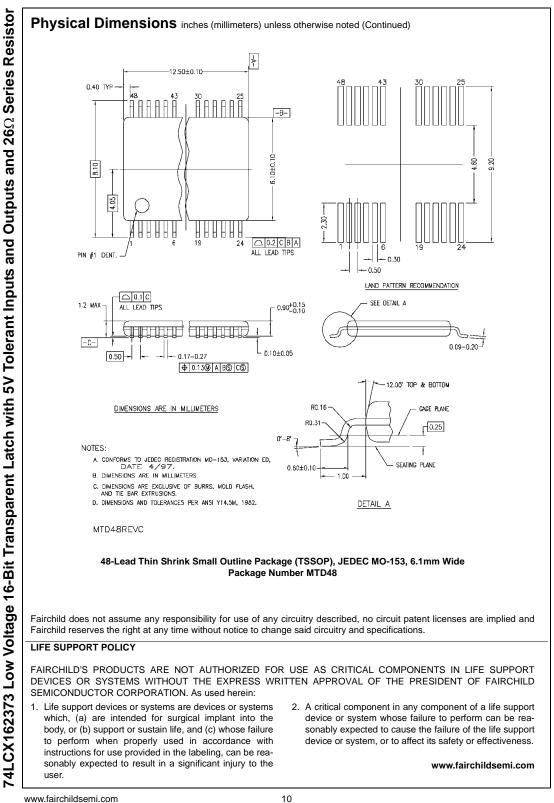




74LCX162373







ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly ori indirectly, any claim of personal injury or death

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: 74LCX162373MTDX 74LCX162373MTD 74LCX162373MEA